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PTO/SB/08A(08/00)

Approved for use through 10/31/2002, OMB 0651-0031

INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(Use as many sheets as necessary)</i>				Application Number		
				Filing Date		12/12/2001
				First Named Inventor		Muffoletto et al.
				Group Art Unit		1745
				Examiner Name		A. Martin
Sheet	3	of	4	Attorney Docket Number		04645.1002

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No. 1	U.S. Patent Document Kind Code 2 Number (if known)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear
ajm	1	5,549,931	Dattatraya et al.	08/27/1996	
	2	5,376,475	Ovshinsky et al.	12/27/1994	
	3	5,702,970	Choi	12/30/1997	
	4	5,576,925	Gorowitz et al.	11/19/1996	
	5	5,616,429	Klementowski	04/01/1997	
	6	5,569,558	Takeuchi et al.	10/29/1996	
	7	5,716,422	Muffoletto et al.	02/10/1998	
	8	6,110,622	Frysz et al.	08/29/2000	

FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. 1	Foreign Patent Document Kind Code5 Office3 Number4 (if known)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear	T6
ajm	9	WO 95/05499	Imperial Chemical Industries	02/23/1995		
	10	EP 0 878 857 A1	Katayama Special Industries Ltd.	11/18/1998		
ajm	11	0 582 844 A1	General Electric Company	07/12/1993		
	12	0 446 584 A1		09/18/1991		

Examiner Signature	<i>A. Martin</i>	Date Considered	9/03
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OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. 1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate, title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T2
gm	13	Thin Film Technology - Chapter 5 - Chemical Methods of Film Formation, pages 255-287	
	14	D.R. ROLISON, K. KUO, M. UMANA, D. BRUNDAGE, AND ROYCE W. MURRAY, Properties of RuOx Working Electrodes in Nonaqueous Solvents, Kenan Laboratories of Chemistry, University of North Carolina, Chapel Hill, North Carolina.	
	15	JOHN M. BLOCHER, JR., Vapor-Deposited Materials, edited by Carroll F. Powell, Joseph H. Oxley, John M. Blocher, JR., Battelle Memorial Institute, Columbus, Ohio, sponsored by The Electrochemical Society, Inc., New York, New York.	
	16	L.L. CHANG, L. ESAKI, W.E. HOWARD, R. LUDEKE, AND G. SCHUL, Structures Grown by Molecular Beam Epitaxy, IBM Thomas J. Watson Research Center, Yorktown Heights, New York.	
	17	P. BIRK and W. WEPPNER, Electrochemical analysis of thin film electrolytes and electrodes for application in rechargeable all solid state lithium microbatteries, Chair for Sensor and Solid State Ionics, Christian-Albrechts-University, Kaiserstr. 2, D-24143 Kiel, Germany	
	18	T. BROUSSE, R. MARCHAND, O RAYMOND, P FRAGNAUD, L. HEIDER and D.M. SCHLEICH, Preparation Of All-Oxide Lithium Ion Microbatteries, ISITEM, Laboratoire de genie des Materiaux, rue Christian Pauc, BP, T. H. Darmstadt, Thin Film Section, Material Science Dept. Petersen Str. 23, Darmstadt, Germany.	
	19	Patent Abstracts of Japan, 11017126, SHARP CORP., Deposition Of Ferroelectric Film and Ferroelectric Capacitor Element.	
gm	20	Patent Abstracts of Japan, 09235118, MURATA MFG CO LTD, Titanium Oxide Film	

Examiner Signature		Date Considered	9-3
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